## NSN 5961-01-333-6201

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-333-6201

**Inclosure Material:** 

Plastic

**Overall Length:** 

Between 14.23 millimeters and 16.51 millimeters

**Terminal Length:** 

Between 12.7 millimeters and 14.73 millimeters

**Overall Height:** 

Between 3.56 millimeters and 4.82 millimeters

**Overall Width:** 

Between 9.66 millimeters and 10.66 millimeters

**Function For Which Designed:** 

Amplifier

**End Application:** 

5865-01-188-3309 an/ulq-1 (v) 1 jammer system respo

**Mounting Facility Quantity:** 

1

**Internal Configuration:** 

Junction contact-darlington connected

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-220ab

**Electrode Internally-electrically Connected To Case:** 

Collector

**Mounting Method:** 

Terminal and unthreaded hole

**Semiconductor Material:** 

Silicon

Voltage Rating In Volts Per Characteristic:

40.0 breakdown voltage, collector-to-emitter, base open

**Current Rating Per Characteristic:** 

8.00 amperes source cutoff current

Power Rating Per Characteristic:

26.0 watts small-signal input power, common-collector absolute

**Transfer Ratio:** 

1000.0 static forward current transfer ratio, common-emitter

**Maximum Operating Tempurature Per Measurement Point:** 

150.0 degrees celsius junction

**Special Features:** 

Junction pattern arrangement: pnp

**Terminal Type And Quantity:** 

3 pin

Specification Data:

80131-release 6713 professional/industrial association specification

## NSN 5961-01-333-6201

Transistor - Page 2 of 2



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N/a

**Unit Of Measure:** 

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Demilitarization:

No

Fiig:

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